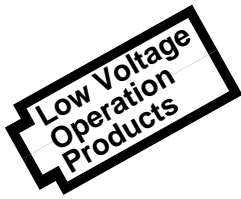


SVM7960C Series

Multi-Melody IC



- 2 Sound Sources
- 127 Words Melody ROM
- Dynamic Loudspeaker Driving Capability
- 4 Melodies Max.(Binary Selection)
or 3 Melodies(Direct Melody Selection)

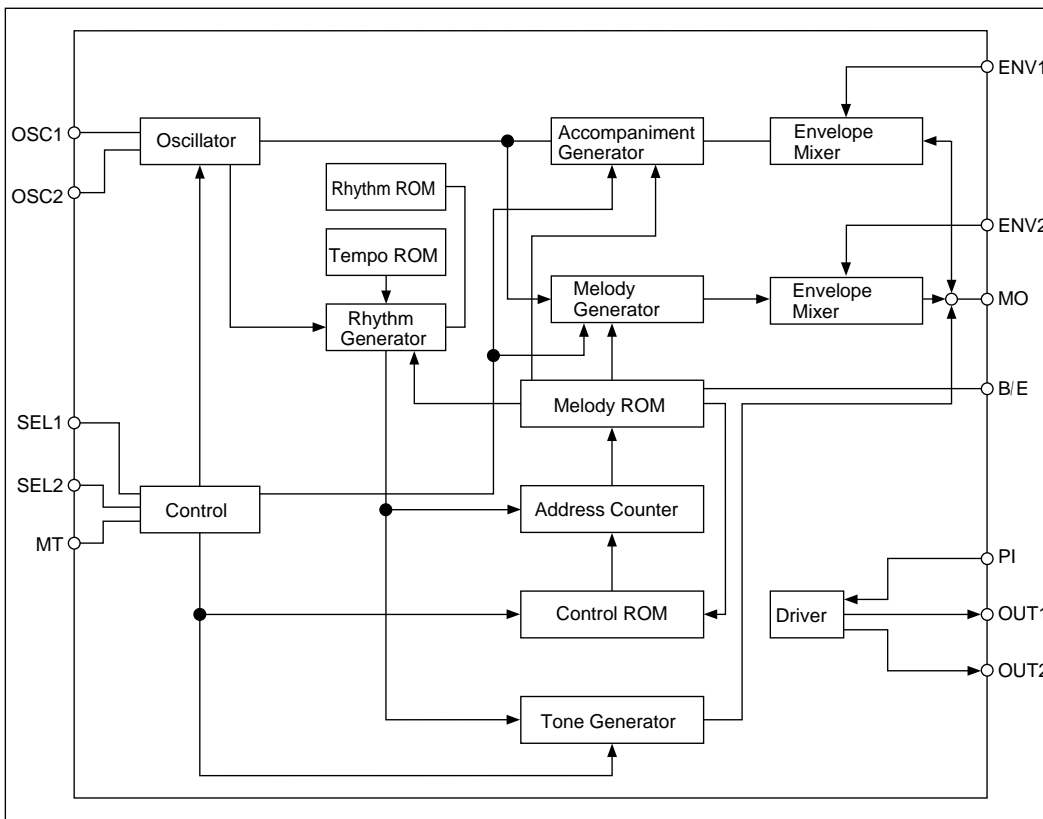
DESCRIPTION

The SVM7960C Series CMOS IC produce melodies or alarm tones from a preprogrammed ROM. The ROM has a capacity of 127 words and can store up to 4 melodies from two sound sources with envelope. The IC can be applied to watches, musical boxes and games. etc. Operation status provide easy installation of SVM7960C Series into microcomputer-applied equipment.

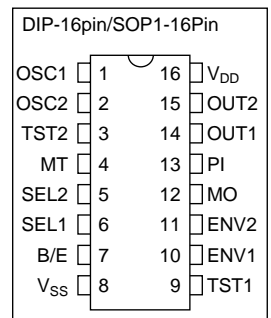
FEATURES

- Melody ROM capacity 127 words
- Up to 4 melodies (3 if it is direct melody selection method) can be performed.
- Two sound sources with envelope (CR envelope)
- DC or AC triggered performance start mode (mask selected)
- Level hold performance or one shot performance (mask selected)
- Equipped with operation status detection terminals (BUSY/END signal) (mask selected).
- Can drive an 8-ohm dynamic loudspeaker if provided externally with a transistor.
- Package DIP-16pin (plastic) /SOP1-16pin(plastic)
- 1.5V/5V operating voltage (mask selected)

BLOCK DIAGRAM



PIN CONFIGURATION



■ PIN DESCRIPTION

Pin No.	Pin name	Pull-down resistor	Function
1	OSC1	-	A resistor is connected between both terminals to form a ring oscillator, or external reference signals are applied to OSC1.
2	OSC2	-	
3	TST2	Provided	LSI test input
4	MT	Provided	For binary selection:Controls start and stop of performance. For direct selection:Selects melody 1 and controls start and stop of its performance.
5	SEL2	Provided	For binary selection:This terminal, in conjunction with SEL1, selects a melody. For direct selection:Selects melody 3 and controls start and stop of its performance.
6	SEL1	Provided	For binary selection:This terminal, in conjunction with SEL2, selects a melody. For direct selection:Selects melody 2 and controls start and stop of its performance.
7	B/E	-	BUSY or END signal output terminal
8	V _{SS}	-	Power supply terminal (0V)
9	TST1	Provided	LSI test input
10	ENV1	-	Connects resistor and capacitor to add envelope to main melody.
11	ENV2	-	Connects resistor and capacitor to add envelope to accompaniment
12	MO	-	Output terminal for acoustic signals that have not been amplified.
13	PI OUT1 OUT2	Provided	Connects PNP/NPN transistors, resistors and capacitors to form a low-frequency linear amplifier circuit.
14			
15			
16	V _{DD}	-	Power supply terminal (+)

■ ABSOLUTE MAXIMUM RATINGS

(V_{SS} =0V)

Rating	Symbol	Value	Unit
Supply voltage	V _{DD}	-0.3 to 7.0	V
Input terminal voltage	V _{IO}	-0.2 to V _{DD} +0.2	V
Operating temperature	T _{opr}	-20 to +85 (V _{DD} 1.5V)	°C
Storage temperature	T _{stg}	-65 to +150	°C
Soldering temperature and time	T _{sol}	260°C, 10s (at lead)	-

■ ELECTRICAL CHARACTERISTICS

●V_{DD}=1.5V, Ta=25 C

(V_{SS} =0V, Ta =25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit		
Operating voltage	V _{DD}		1.2	1.5	3.5	V		
"1" input voltage	V _{IH}		V _{DD} -0.3	-	V _{DD}	V		
"0" input voltage	V _{IL}		V _{SS}	-	V _{SS} +0.3	V		
"1" input current (1)	I _{IH1}	V _{IH1} =V _{DD} , during performance, either by binary or terminal selection, at SEL1/SEL2	V _{DD} =1.5V	0.6	2.0	6.0	μA	
"1" input current (2)	I _{IH2}	MT V _{IH2} =V _{DD}	V _{DD} =1.5V	0.6	2.0	6.0	μA	
"1" input current (3)	I _{IH3}	PI V _{IH3} =V _{DD}	During standby	V _{DD} =1.5V	2.0	6.0	20	μA
			During performance	V _{DD} =1.5V	-	-	0.05	μA
"1" input current (4)	I _{IH4}	V _{IH4} =V _{DD} , during standby, by binary selection, at OSC1/SEL1/SEL2	V _{DD} =1.5V	-	-	0.05	μA	
"0" input current	I _{IL}	SEL1, SEL2, MT, PI, OSC1 V _{IL} =V _{SS}	V _{DD} =1.5V	-	-	0.05	μA	
"1" output current (2)	I _{OH2}	B/E, bipolar transistor V _{BE} =0.7V	V _{DD} =1.2V	6.0	20	60	μA	
"0" output current (3)	I _{OL3}	OUT2, bipolar transistor V _{BE} =0.7V	During standby	V _{DD} =1.5V	-	-	1.5	μA
			During performance	V _{DD} =1.5V	100	300	750	μA
"1" output current (4)	I _{OH4}	OUT2, bipolar transistor V _{BE} =0.7	V _{DD} =1.2V	100	300	750	μA	
Input amplitude	A _I	V _{DD} 1.5V, when external reference signal is applied to OSC1	V _{DD} ±0.4	-	-	V		
Average Current Consumption in standby mode	I _S	All terminals open	V _{DD} =1.5V	-	-	0.3	mA	
		Standard circuit connected, SEL1, SEL2, MT terminals open	V _{DD} =1.5V	-	-	3.0	μA	
Average Current Consumption in performance mode	I _O	f _{OSC} =32kHz All terminals,except MT, open	V _{DD} =1.5V	-	50	100	μA	

●V_{DD}=5.0V

(V_{SS} =0V, Ta =25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit		
Operating voltage	V _{DD}		3.0	5.0	5.5	V		
"1" input voltage	V _{IH}		V _{DD} -0.3	-	V _{DD}	V		
"0" input voltage	V _{IL}		V _{SS}	-	V _{SS} +0.3	V		
"1" input current (1)	I _{IH1}	V _{IH1} -V _{DD} , during performance, either by binary or terminal selection, at SEL1/SEL2	V _{DD} =5.0V	10	30	100	μA	
"1" input current (2)	I _{IH2}	MT	V _{IH2} =V _{DD} V _{DD} =5.0V	5	15	50	μA	
"1" input current (3)	I _{IH3}	P V _{IH3} =V _{DD}	During standby	V _{DD} =5.0V	60	200	600	μA
			During performance	V _{DD} =5.0V	-	-	0.1	μA
"1" input current (4)	I _{IH4}	V _{IH4} -V _{DD} , during standby, by binary selection, at OSC1/SEL1/SEL2	V _{DD} =5.0V	-	-	0.1	μA	
"0" input current	I _{IL}	SEL1, SEL2, MT, PI, OSC1 V _{IL} =V _{SS}	V _{DD} =5.0V	-	-	0.1	μA	
"1" output current (2)	I _{OH2}	B/E, bipolar transistor V _{BE} =0.7V	V _{DD} =4.5V	0.3	0.9	1.8	mA	
"0" output current (3)	I _{OL3}	OUT1	V _{DD} =5.0V	-	-	8.0	μA	
		Bipolar transistor V _{BE} =0.7V	V _{DD} =4.5V	0.8	2.0	4.0	mA	
"1" output current (4)	I _{OH4}	OUT2, bipolar transistor V _{BE} =0.7	V _{DD} =4.5V	0.8	2.0	4.0	mA	
Input amplitude	A _I	V _{DD} 1.5V, when external reference signal is applied to OSC1	$\frac{V_{DD}}{2} \pm 0.4$	-	-	V		
Average Current Consumption in standby mode	I _S	All terminals open	V _{DD} =5.0V	-	-	0.5	μA	
		Standard circuit connected, SEL1, SEL2, MT terminals open	V _{DD} =5.0V	-	10.0	-	μA	
Average Current Consumption in performance mode	I _O	f _{OSC} =32kHz All terminals, except MT, open	V _{DD} =5.0V	-	1	2	mA	

■ OSCILLATION CHARACTERISTICS

●V_{DD}=1.5V

(V_{SS} =0V, Ta =25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation frequency	f _{OSC}	V _{DD} =1.5V, VR ₁ =750k	-	32.768	-	kHz
Oscillation self-excited voltage	V _{STA}	VR ₁ =750k	1.2	-	-	V
Oscillation stop voltage	V _{STP}	VR ₁ =750k	-	-	1.2	V

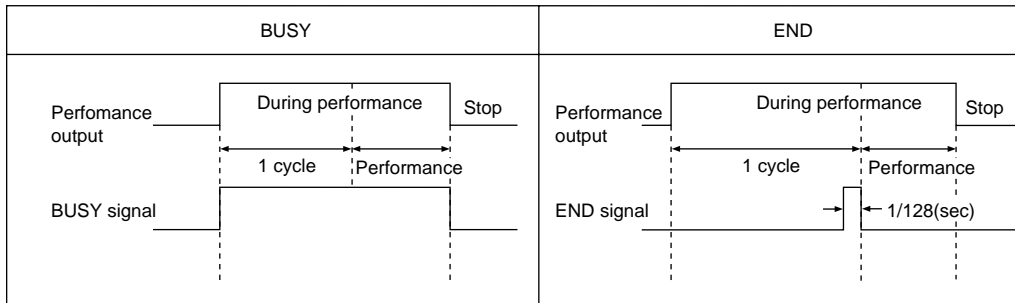
●V_{DD}=5.0V

(V_{SS} =0V, Ta =25°C)

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Unit
Oscillation frequency	f _{OSC}	V _{DD} =5.0V, VR ₁ =820k	-	32.768	-	kHz
Oscillation self-excited voltage	V _{STA}	VR ₁ =820k	1.2	-	-	V
Oscillation stop voltage	V _{STP}	VR ₁ =820k	-	-	1.2	V

■ MONITOR OUTPUT (BUSY/END TERMINALS)

The SVM7960 has an operation status monitoring output terminal. Either BUSY or END signals can be selected by mask selection.



The pulse width of the END signal is for $f_{OSC}=32.768\text{KHz}$. Both BUSY and END can be output with inverted phases.

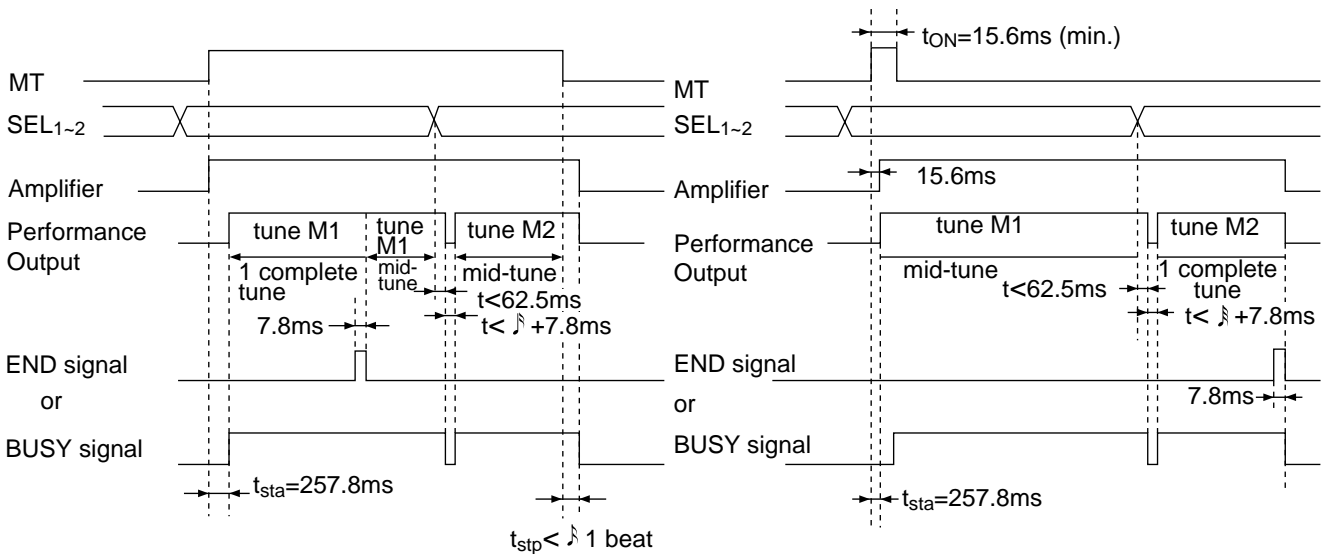
■ TIMING CHART

DC Level-hold

Binary DC level ($f_{OSC}=32.768\text{kHz}$)

DC One-shot

Binary DC one-shot ($f_{OSC}=32.768\text{kHz}$)



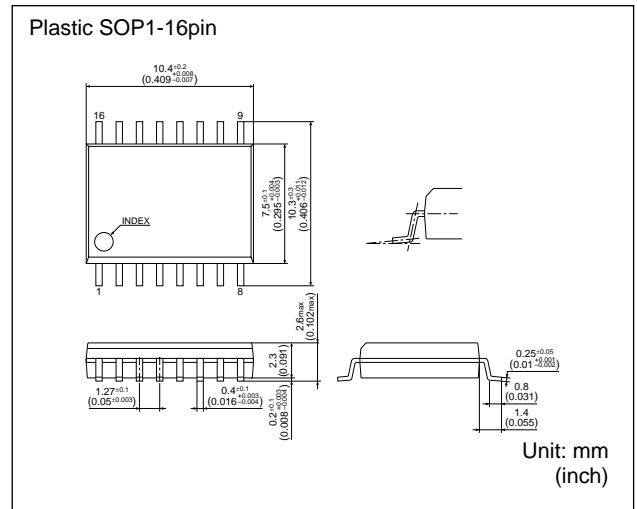
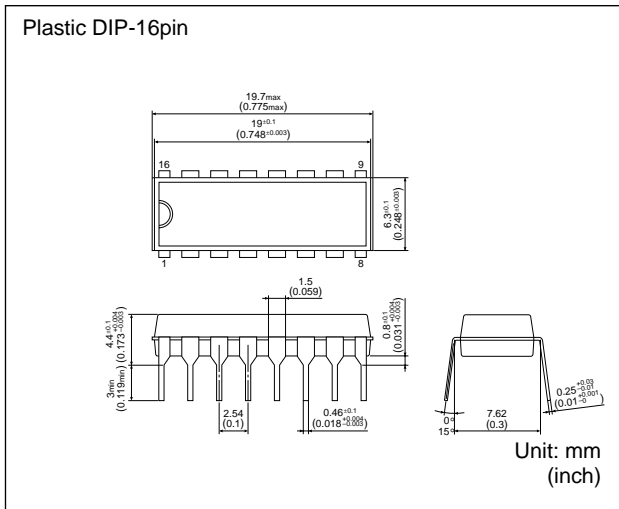
■ LINE UP

Model	Oscillation frequency	Performance mode	Melody selection
SVM7960	External reference signal	Level hold	Binary code selection
SVM7961		One shot	
SVM7962	CR oscillation	Level hold	
SVM7963		One shot	
SVM7964	External reference signal	Level hold	Direct selection
SVM7965		One shot	
SVM7966	CR oscillation	Level hold	
SVM7967		One shot	

The models are further classified into the following types according to their functions:

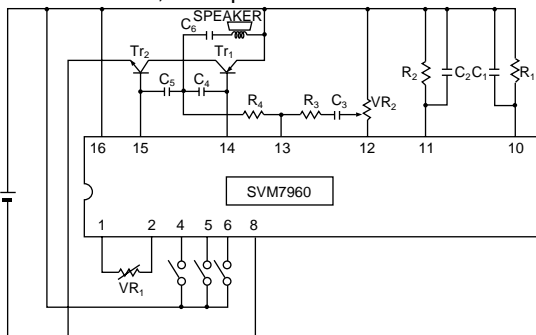
Performance start input signal Melody switching B/E output terminal	AC input		DC input	
	Possible	Impossible	Possible	Impossible
BUSY output	A	B	C	D
END output	E	F	G	H

■ PACKAGE DIMENSIONS



■ BASIC EXTERNAL CONNECTION

CR oscillation, DC input



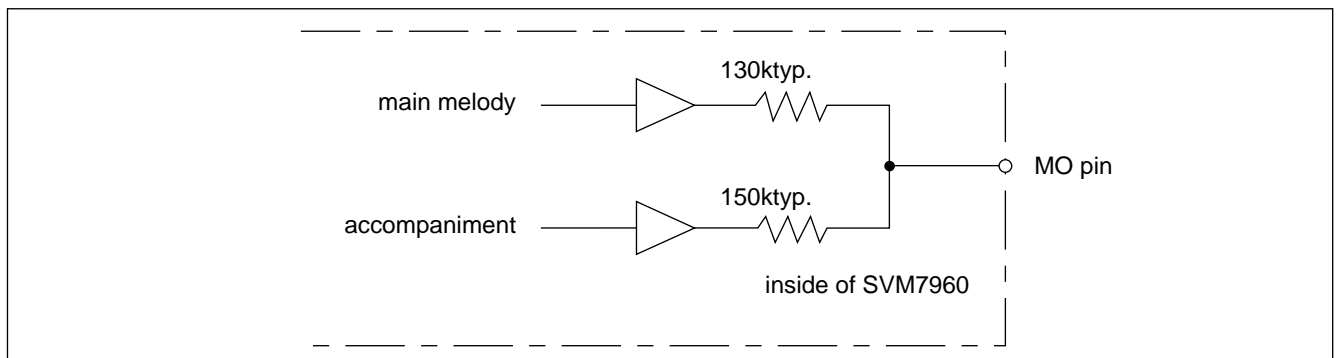
Note: Don't touch the oscillation circuit with your hand while playing musical tunes or activating "MT" signal
 The oscillation resistor(VR1) should be covered with resin or others.
 Justly settle power supply (dry cells), not so as to chatter (over than 10 msec).
 Disconnect "MT" to V_{DD} in case of level hold type or switch the power supply off, when anything unusual should happen.
 Don't make bonding to pads of "OSC1" and "OSC2" when you assemble SVM7900 (including CR for oscillation on chip).

■ RECOMMENDED CONDITIONS FOR EXTERNAL DEVICES

Symbol	Ratings	Unit	Symbol	Ratings	Unit
VR ₁	1 Note:	M	C ₃	0.1	μF
VR ₂	50	k	C ₄	0.01 to 0.047	μF
R ₁	100	k	C ₅	0.01 (or nothing)	μF
R ₂	100	k	C ₆	100 to 300	μF
R ₃	51 to 150	k	SPK	8	
R ₄	510	k	Tr ₁	PNP DCh _{FE} ≧160	-
C ₁	4.7	μF	Tr ₂	NPN DCh _{FE} ≧160	-
C ₂	4.7	μF			

Note: Typically 750k-ohms when V_{DD}=1.5V
 Typically 820k-ohms when V_{DD}=5.0V

■ MO OUTPUT PIN EQUIVALENT CIRCUIT



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